

## Electronic Patent Application Fee Transmittal

<b>Application Number:</b>	10849617
<b>Filing Date:</b>	20-May-2004
<b>Title of Invention:</b>	Methods of fabricating nitride-based transistors having regrown ohmic contact regions and nitride-based transistors having regrown ohmic contact regions
<b>First Named Inventor/Applicant Name:</b>	Adam William Saxler
<b>Filer:</b>	Elizabeth A. Stanek/Erin Dutton
<b>Attorney Docket Number:</b>	5308-413

Filed as Large Entity

### Utility Filing Fees

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
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**Basic Filing:**

**Pages:**

**Claims:**

**Miscellaneous-Filing:**

**Petition:**

**Patent-Appeals-and-Interference:**

Notice of appeal	1401	1	500	500
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Post-Allowance-and-Post-Issuance:

**Extension-of-Time:**

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
<b>Miscellaneous:</b>				
<b>Total in USD (\$)</b>				<b>500</b>